LBI-31584A



### **MAINTENANCE MANUAL**

# 150-174 MHz SYNTHESIZER/INTERCONNECT BOARD

# 19D900961 G2 & G5, WIDEBAND

### PSX-200

TABLE OF CONTENTS	
	Page
SPECIFICATIONS	
DESCRIPTION	
CIRCUIT ANALYSIS	1
OUTLINE DIAGRAM	
SCHEMATIC DIAGRAM	
PARTS LIST	13-16

## DESCRIPTION

The Synthesizer/Interconnect board for the PSX-200 two-way radio is microcomputer controlled. A phase locked loop synthesizer generates the transmitter and receiver frequencies in a common voltage controlled oscillator (VCO). The VCO frequency range is approximately 150-174 MHz for transmit, 195-219 MHz for receive. The microcomputer also controls the generation of Channel Guard tones and provides the carrier control timer in the transmit mode.

It contains interface circuitry for voltage protection and level shifting, an audio processor, a microcomputer, a frequency synthesizer, a microphone preamplifier, and an electrically erasable PROM (EEPROM). The EEPROM stores the binary data for the transmit and receive frequencies, Channel Guard tones and the CCT delay on a per channel basis. A block diagram of the Synthesizer/Interconnect board is shown in Figure 1.

# — NOTE —

The EEPROM provides the user with the capability to reprogram the EE PROM to meet changing individual system requirements.

Programming for the EEPROM is accomplished by connecting the PROM Programmer to the rear radio connector. The PROM can then be read or programmed as desired.

Programming information for the EEPROM is included in the instruction manual for the Programmer.

In addition to providing the normal radio functions, the microcomputer has the ability to execute a maintenance diagnostic instruction set to aid in troubleshooting the radio. Further details are included in the Service Section of this manual.

# CIRCUIT ANALYSIS

# CHANNEL SELECT

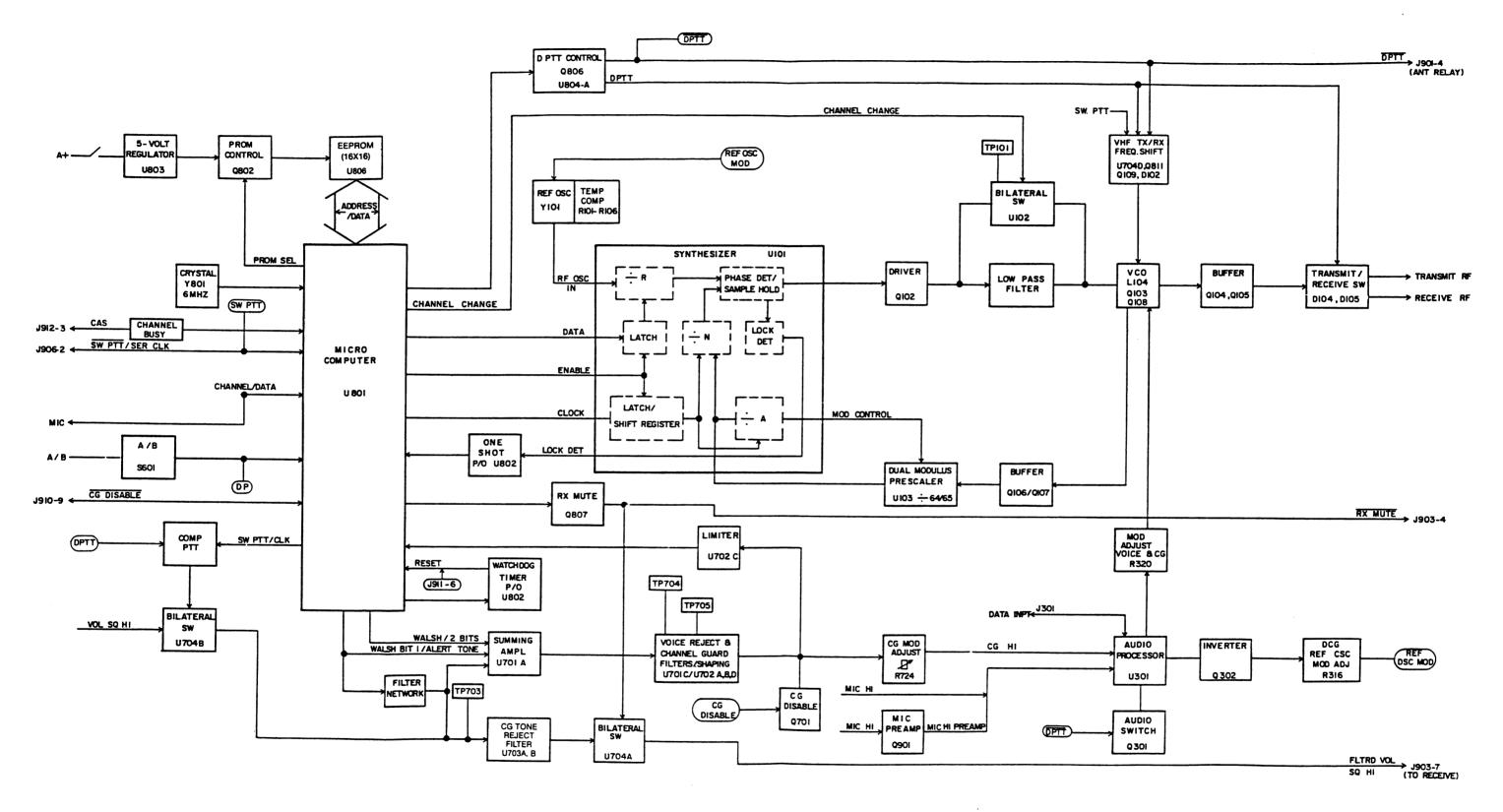
Frequency selection is controlled by Mode A/B switch S601 in the receive circuit, on the Tx/Rx board. When pressed, A- is applied to microcomputer U801-37 causing the microcomputer to select channel 2 (Mode B).

When the channel select switch is released, the microcomputer applies +5 VDC to the EEPROM through Q802. The frequency bit code corresponding to channel 1 (Mode A) is then loaded into the synthesizer.

# CHANNEL BUSY INDICATOR

Channel Busy indicator H2 is controlled by the CAS line and is turned on when the selected channel is busy. Hole HL94 is provided to allow the option indicator to be controlled by an alternate signal.

1



RC-5196

Figure 1 - Synthesizer/Interconnect Board

MODE A/B

The Mode A/B switch S601, located on the transmit/receive board, may be used to provide mobile-to-mobile communications through an intermediate repeater (repeated path) or direct mobile-to-mobile communications. For example: channel 1 (Mode A) may be programmed for the repeater frequency (repeated path) while channel 2 (Mode B) would be programmed for the mobile receive frequency (direct path). Judicious programming will allow selection of repeated or direct communication paths on selected channels.

# MICROCOMPUTER CONTROL SYSTEM

The microcomputer responds to the manually initiated functions of the Push-to-talk and the Mode A/B. All other operations occur automatically and are controlled by the microcomputer.

When the PTT switch is pressed A- is applied to microcomputer U801-38 from J911-2. The microcomputer immediately mutes the receiver by turning on Q807 which provides a low level to J903-4 to mute the receiver. The microcomputer then delays 10 milliseconds before loading the synthesizer with the transmit bit code. This allows the audio amplifier to be turned off before the synthesizer frequency is changed. After this delay the microcomputer turns on PROM power switch Q802, applying +5V to EEPROM U806. The transmit bit code is then loaded in series from the PROM into the microcomputer and then serially into the frequency synthesizer over the clock and data input lines.

Once the bit stream is loaded into the synthesizer an enable pulse and a 10 millisecond channel change pulse is provided to allow the synthesizer to generate the correct RF frequency. The microcomputer immediately begins monitoring the LOCK DET line to verify that the synthesizer is 'on' frequency. If the synthesizer is not locked on the correct frequency negative pulses will be present on the LOCK DET line and the microcomputer will reload the synthesizer in an attempt to lock it on frequency. If the synthesizer is locked on the correct frequency, the microcomputer will key the transmitter by pulling the input line to inverter U804A low. This allows the output of U804A to rise to +8.5 VDC, forward biasing transmit select diode D104, permitting the synthesizer generated RF frequency to pass through to the exciter through P151. Typical attack time of the transmitter is 50 milliseconds.

At the same time transistor Q806 is turned on, applying  $\overline{\text{DPTT}}$  to audio switch

Q301. Q301 is also turned off, removing the 'short' from amplifier U301A and enabling the audio processor.

# WATCHDOG TIMER

The watchdog timer consisting of reset switch Q803 and timer U802, monitors the operation of the microcomputer and generates a reset pulse in the unlikely condition that the microprocessor fails to function properly.

When the microcomputer is operating properly, reset pulses from U801-35 are applied to the base of reset switch Q803 through delay network R836 and C805. Q803 turns on, grounding the clock timer input which, in turn, holds the microcomputer RESET input high.

When the microcomputer is not functioning properly, the reset pulses will not be present. Q803 will turn off and the timer will generate a square wave to reset the microcomputer.

### FREQUENCY SYNTHESIZER

The frequency synthesizer generates the transmit and receive frequencies for all channels under control of the microcomputer. The frequency synthesizer consists of a reference oscillator Y101, synthesizer IC U101, bilateral switch U102, low pass filter, VCO -Q103, and -Q108, buffers -Q104, -Q107, and high speed dual modulus counter U103.

# Reference Oscillator

The reference oscillator consists of Y101, a junction FET Q101, varicap D101, tuned coll L101, and associated circuitry. The 5 PPM Colpitts oscillator operates at a frequency of 13.2 MHz. Voltage is provided by the 8.5V continuous supply. A temperature compensation network consisting of R101 thru R106, provides a temperature compensated voltage to varicap D101 to maintain the correct frequency. The temperature compensator, utilizing an inverse DC S-curve output characteristic, varies the output voltage to the varicap as a function of temperature. The temperature compensation network maintains frequency over a temperature range of -30°C to +60°C (-22°F to +140°F). The varicap is also used to modulate the oscillator.

Diode D108 produces a negative DC level at the gate of FET Q101 depending on the amplitude of the oscillations. This, in effect, produces a negative feedback, RF to DC, and prevents the oscillator from going into limiting. Slug tuned coil L101 sets the frequency of the oscillator. Modulation voltage

for the reference oscillator is adjusted by R316 in the audio processor and applied to varicap D101 through C101 and R109. R316 adjusts the deviation. Refer to the service section for adjustment procedures.

The synthesizer contains three dividers, a phase detector, two shift registers, and a lock detect circuit. When the PTT switch is pressed (transmit), released (receive), or a different channel selected, new frequency data is received on the clock, data, and enable lines and the synthesizer immediately begins generating the new RF frequency. This serial data determines the VCO frequency by setting the internal dividers. The reference oscillator frequency applied to the programmable divide by R counter is divided down to some lower frequency as indicated by the input data and applied to the internal phase detector.

The phase detector compares this signal with the output of the internal - N counter. The output of the - N counter is a function of the RF frequency which is divided down by the dual modulus prescaler and the - N counter. When operating on the correct frequency the inputs to the phase detector are identical and the output voltage of the phase detector is constant. Under these conditions, the VCO is stabilized or locked on frequency. If the compared frequencies (phases) differ a  $\pm$  error voltage is generated and applied to Q102. This error voltage is then supplied to the VCO through the frequency acquisition circuit and low pass filter. The capacitance of varicaps D106 and D109 vary in accordance with the applied error voltage thereby resetting the VCO to the correct frequency. Capacitor C116 is a holding capacitor to store the 'hold' voltage for the phase detector/sample and hold circuit. C117 is a ramp capacitor which also is part of the sample and hold circuit. The value of C117 determines the rate of charge of the ramp.

The lock detect line provides lock status information to the microcomputer through a one shot (part of U802).

#### Acquisition and Low Pass Filter

The output of the synthesizer is applied through buffer Q102 to the low pass filter. The low pass filter consisting of R118-R120, and C119-C121 eliminates undesired pulses on the VCO error control line to provide a constant DC level to frequency adjusting varicaps D106 and D109.

When a channel change pulse is received bilateral switch U102 is turned on to bypass the low pass filter effectively increasing the bandwidth and decreasing

channel acquisition time. The channel change pulse is 10 milliseconds wide.

### Voltage Controlled Oscillator VCO

The VCO is a wide range JFET oscillator with an operating range of 195-219 MHz. The frequencies for VHF are 150-174 MHz in transmit and 195-219 MHz in receive. The divided down reference frequency is 5 kHz. A simplified diagram of the VCO is shown in Figure 2. It consists of Q103, Q108, L104, L103, L111, D106, D107, and D109 and associated circuitry. VCO frequency is controlled by an error control voltage from the synthesizer and varicaps D106, D107 and D109. Frequency range centering is provided by L104. Audio modulation is provided by the audio processor and applied to the VCO through C122.

The output of the VCO is taken from the drain of Q103 and applied to RF output buffers Q104 and Q105. These buffers provide drive for receiver injection, transmitter exciter, and feedback buffers Q106 and Q107.

A transmit/receive PIN diode switch, D104 and D105, directs the RF output to the transmitter or receiver. The switch is controlled by the DPTT signal from the microcomputer. When DPTT is high, D104 conducts and RF is fed to the transmitter and to the receiver when DPTT is low allowing D105 to conduct.

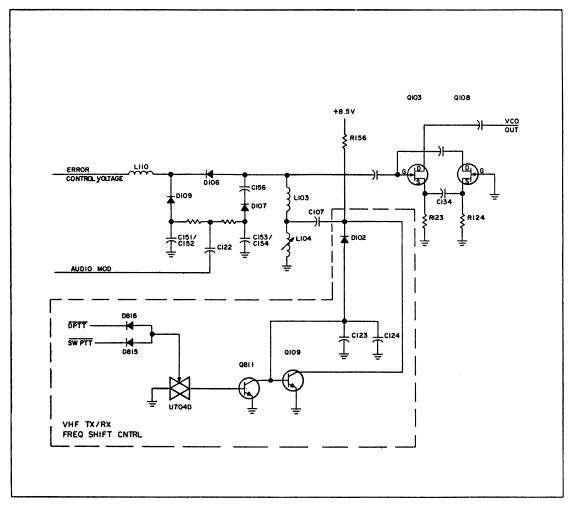
# Dual Modulus Counter

The VCO frequency is fed back to dual modulus counter, U103, through buffers Q107 and Q106. The counter divides the VCO frequency by 64 or by 65 depending on the status of the modulus control line. The divided down reference frequency is 5.0 kHz when operating in the 150-174 MHz band.

The output of the dual modulus counter is applied to the - N counter in the synthesizer. It is then divided down and compared in frequency and phase with the divided down frequency from the reference oscillator. The - N count is set by the microcomputer.

# VHF Transmit/Receive Frequency Shift

In VHF radios the VCO frequency is shifted approximately 45 MHz between the transmit and receive modes. The frequency shift is controlled by the PTT circuits. In the transmit mode the VCO operates between 150-174 MHz, while in the receive mode it operates between 195-219 MHz. The Tx/Rx frequency shift circuit is comprised of bilateral switch U704D, Q811, Q109, and diode switch D102. This circuit is operable in VHF radios only and is disabled by removing cable W802 connected between H21 and H22.



RC 4403A

Figure 2 - VCO Simplified Diagram

In the receive mode the PTT circuits are inactive. U704D is on, Q811 is off, and Q109 is on. Diode switch D102 is forward biased connecting capacitors C123 and C124 across tunable coil L104. These two capacitors provide an AC short across L104, electrically removing it from the circuit and shifting the VCO operating range to 195-219 MHz.

In the transmit mode the PTT lines are low. U704D is off, Q811 is on, and Q109 is off. Diode switch D102 is reverse biased, electrically disconnecting the AC shorting capacitors (C124 and C123) from across tunable coil L104. This lowers the VCO operating frequency to the 150-174 MHz range.

# MICROPHONE PREAMPLIFIER

A preamplifier stage (Q901 and associated circuitry) is provided for the standard electret microphone without a built-in preamplifier.

With this microphone, MIC HI is coupled through J911-5 to the preamplifier stage. The amplified output is coupled through C312 and R301 to the audio processor.

For optional microphones with a built-in preamplifier, audio is coupled through J911-4, bypassing MIC PRE AMP Q901.

## Audio Processor

The audio processor provides audio pre-emphasis with amplitude limiting and post limiter filtering. A total gain of approximately 24 dB is realized through the audio processor. 20 dB is provided by U301B and 4 dB by U301A.

The 8.5 Volt regulator powers the audio processor and applies regulated +8.5V through J903-2 to a voltage divider consisting of R306 through R309. The +4.25V output from the voltage divider at

the junction of R307 and R308 establishes the operating reference point for both operational amplifiers. C305 provides an AC ground at the summing input of both operational amplifiers.

Audio direct from the microphone is coupled to the audio processor through C313 and R302 to the input of operational amplifier U301B-6.

When the input signal to U301B-6 is of a magnitude such that the amplifier output at U301B-7 does not exceed 4 volts P-P, the amplifier provides a nominal 20 dB gain. When the audio signal level exceeds 4 volts peak-to-peak, diodes D301 and D302 conduct on the positive and negative half cycles providing 100% negative feedback to reduce the amplifier gain to 1. This limits the audio amplitude at U301B-7 to 5 volts peak-to-peak.

Resistors R303, R304, R305, and capacitor C302 comprise the audio preemphasis network that enhances the signal to noise ratio. R304 and C302 control the pre-emphasis curve below limiting. R305 and C302 control the cut-off point for high frequency pre-emphasis. As high frequencies are attenuated, the gain of U301B is increased.

The amplified output of U301B is coupled through C307, R313 and R314 to a second operational amplifier U307A.

The Channel Guard tone and data inputs are applied to U301A-2. The CG tone (or data) is then combined with the microphone audio.

A post limiter filter consisting of R314, R313, R315, C308 and C309 provide 12 dB per octave roll-off. R313 and C307 provide an additional 6 dB per octave roll-off for a total of 18 dB.

# - SERVICE NOTE -

R313-R315 are 1% resistors. This tolerance must be maintained to assure proper operation of the post limiter filter. Use exact replacements.

The audio processor output is coupled through J302 to the transmitter. R316 and R320 are output level adjustment controls to set the modulation sensitivity for the VCO and reference oscillator.

Shorting switch Q301 is turned on in the receive mode (DPTT is high) to short

out U301-A and prevent any interference from the transmit audio circuits.

#### CHANNEL GUARD

Channel Guard provides a means of restricting calls to specific radios through the use of a continuous tone coded squelch system (CTCSS). Tone frequencies range from 71.9 Hz to 210.7 Hz. The Channel Guard tone frequencies are software programmable. These frequencies are listed in the Programmers Manual.

The microcomputer selects the assigned tone information from the EEPROM memory for each channel, transmit and receive, and generates the Channel Guard signal. This signal is applied as Walsh Bit 1 and 2 to summing amplifier U701A. These two bits are summed together and filtered to provide a smooth sine wave for tone Channel Guard.

The switched volume/squelch Hi signal to the summing amplifier is controlled by bilateral switch U704B. In the encode mode COMB DPTT is low turning U704B off and preventing any input from the SW Vol/Sq Hi line from interfering with the encoding signal.

The output of summing amplifier U701A is applied to buffer/amplifier U702B through a two-pole active voice reject filter consisting of U701B and C and U702A and D. The active filter shunts all frequencies above 300 Hz to ground, thereby preventing those frequencies from interfering with the encoded signal. The output of U702B is the assigned CG tone. This signal is applied to the audio processor through CG deviation control R724. Channel Guard deviation is set for 0.75 kHz.

# CG Decode

In the decode mode, COMB DPTT is high. U704B is turned on and audio from the SW Vol/Sq Hi line is applied to summing amplifier U701A through bilateral switch U704B. This signal is amplified and filtered by U701A, B, C and U702A, B and D, so that only the CG signal (if present) is applied to hard limiter U702C. The CG signal is squared up for comparison by the microcomputer to determine if the CG signal is correct. If the microcomputer determines the CG signal to be correct, RX Mute transistor Q807 is turned off. The Rx Mute line is pulled high by pull up resistor R715. This turns on bilaterial switch U704A and allows the audio on the FLTRD VOL/SQ HI line to pass through to the receiver.

CIRCUIT ANALYSIS

LBI-31584

CHANNEL GUARD (CG) DISABLE

The CG DIS line has a double function. It can disable the encode or the the radio is on hook or off hook. When decode CG function. The encode disable Channel Guard is disabled (off hook) the function is controlled by the PTT switch while the decode function is disabled signal. The RX MUTE line is high, as within the microcomputer <u>software</u>. To would be normally expected. The Channel disable the decoder, the <u>CG DIS/SER CONTL</u> Guard decoder is looking for the STE line should be grounded. The micro- burst (phase reversal in tone Channel computer will detect that the line is Guard). If an STE burst is detected, the low, and turn RX MUTE transistor Q807 RX MUTE line will go low for about 200 off. The decode filter/limiter circuit ms. This will prevent the squelch tail is not affected, it continues to operate. from being heard. After 200 ms, the RX The detection software also does not stop MUTE line will go high again; by now the working. This allows the off hook STE to transmission has ended and the squelch function.

(>8.5V), the microcomputer does not sense of looking at it: the radio will go quiet any changes. It is buffered by protect for 200 ms any time STE is detected. If tion diode D810. Channel Guard disable it was on hook it will stay quiet after transistor Q701 will turn on when the CG the 200 ms, if it was off hook it will DIS line goes above 8.5 V and shorts the revert to noise squelch operation. STE output of the filter to ground. This operates only on the tone the radio is disables the encoder by preventing any signal from going out on CG HI and will also disable the decoder since no limited programmed to receive and the microphone CG tone will go to the microcomputer. is off-hook, STE will not be active. The receiver will be muted since no CG is CDCSS STE works regardless of the code. decoded. Disabling the decoder this way will never allow the audio to open up, while taking the radio off hook (pulling CG DIS low) will always make the radio open up. Turning CG Disable transistor Q701 on causes the DC bias to change. It will take 2 or 3 seconds for the bias to restore itself after the encoder is disabled.

# SQUELCH TAIL ELIMINATION (STE)

STE eliminates squelch tails when decoder is still looking at the received will hold the audio closed. The off hook STE does not affect the operation of the When the CG DIS line is pulled high Channel Guard while on hook. Another way programmed to receive. If the signal has a Channel Guard tone the radio is not

# CARRIER CONTROL TIMER

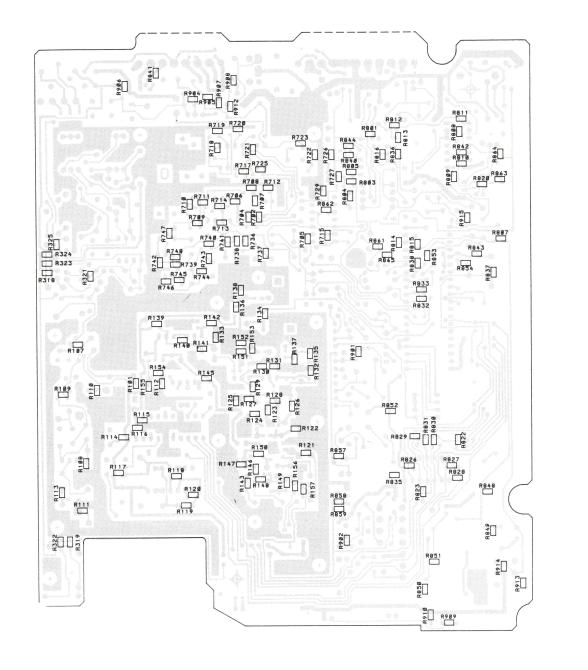
The Carrier Control Timer (CCT) is contained within and controlled by the microcomputer. Each time the PTT switch is activated, an internal counter begins to count down. If the counter times out, the transmitter is unkeyed and a 100 mV rms, 1 kHz tone is sounded until the microphone is unkeyed. The CCT is set for 1 minute.

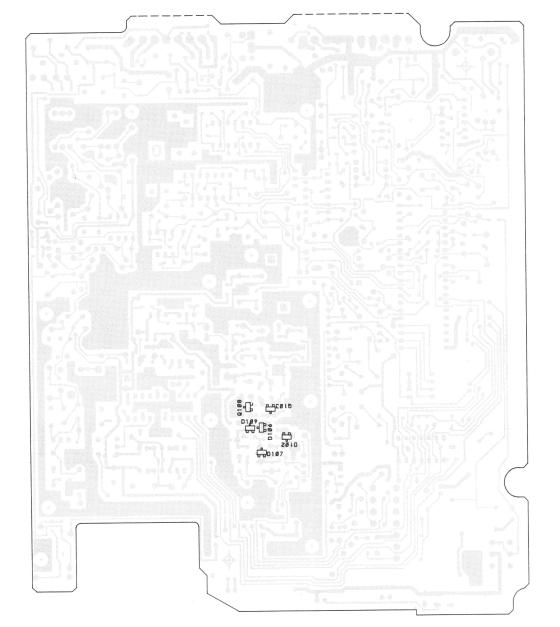


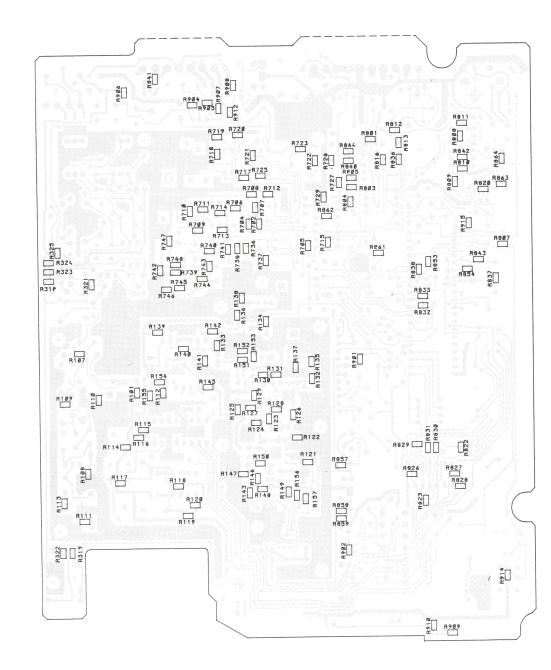
**Ericsson GE Mobile Communications Inc.** 

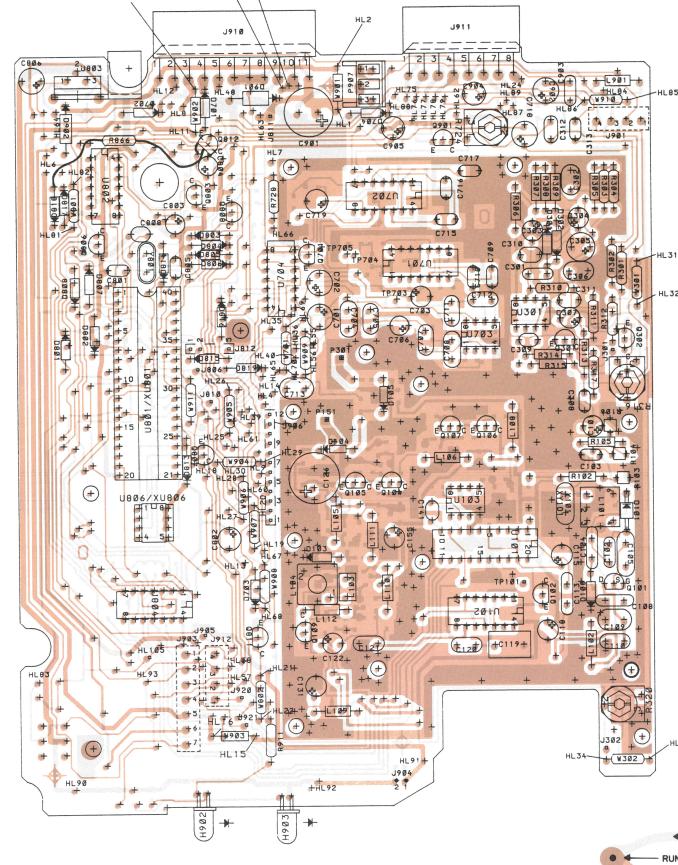
Mountain View Road • Lynchburg, Virginia 24502

Printed in U.S.A.











BACK VIEW OF COMPONENT BOARD FOR PT. /

BACK VIEW OF COMPONENT BOARD

BACK VIEW OF COMPONENT BOARD FOR PT.23

LEAD IDENTIFICATION FOR

(SOT) TRANSISTORS

(TOP VIEW)

(19D900961, Sh. 4, Rev. 11)

(19A704833, Sh. 3&4, Rev. 0)

2

1 + NC

(19D900961, Sh. 7, Rev. 0) (19A704833, Sh. 3 & 4, Rev. 0) (19D900961, Sh. 8, Rev. 1) (19A704833, Sh. 3&4, Rev. 0)

**OUTLINE DIAGRAM** 

WIDEBAND SYNTHESIZER/INTERCONNECT BOARD

8 Issue 2

(19D901717, Rev. 1) (19A704833, Sh. 1&2, Rev. 0) RUNS ON SOLDER SIDE

RUNS ON BOTH SIDES

RUNS ON COMPONENT SIDE

### TABLE OF CONTENTS

NOTES & CHARTS	SHEE!
SYSTEM	2
FUNCTION	CPNT Series
CG TONE REJECT FILTER S SV REGULATOR SYSTEM	700 800 900
SYSTEM/REF OSC	3
FUNCTION	CPNT Series
SYNTHESIZER REF OSC TX AUDIO PROCESSOR SYSTEM CONTROL SYSTEM	100 300 800 900
SYNTHESIZER/C.G	4
FUNCTION	CPNT Series
SYNTHESIZER Channel Guard	100 700
SYSTEM	5
FUNCTION	CPNT SERIES
MICROCOMPUTER CONTROL MULTI FREQ DISPLAY	800 A901

DEVICE	5V PIN NO	8.5V CONT PIN NO	8.5V SYN	GND PIN NO
U102	TIN NO	7 11 110	14	7
U301		8		4
U701		4		11,12,13
U702		4		1 1
U703		θ		4
U704		14		7
U804	14			7
U806	6.7.8			5

#### SPARE IC FUNCTION

DEVICE	INPUT	OUTPUT
	PIN NO	PIN NO
U701-D	12,13	1 4

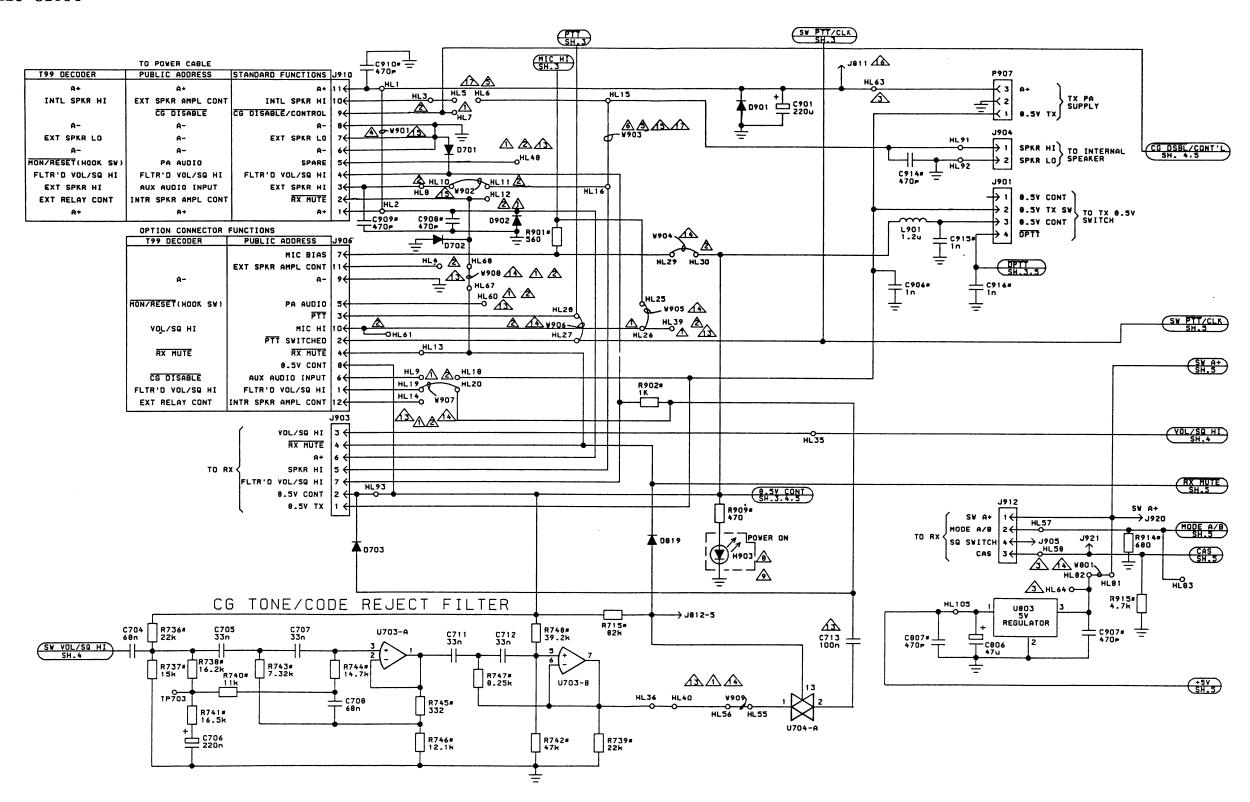
ALL CHIP RESISTORS ARE 1/8 WATT.
ALL RESISTORS ARE 1/4 WATT UNLESS OTHERWISE SPECIFIED.
RESISTOR VALUES IN A UNLESS FOLLOWED BY MULTIPLIER k, OR M.
CAPACITOR VALUES IN F UNLESS FOLLOWED BY MULTIPLIER u, n OR, p.
INDUCTANCE VALUES IN H UNLESS FOLLOWED BY MULTIPLIER m, n OR u.

MODEL NO. REV. LETTER 19090096162 C 19090096165 C		
	MODEL NO.	REV. LETTER
19D900961G5 C	19D900961G2	С
	190900961G5	C

#### NOTES:

- ## FOR T99 DECODER, ADD JUMPERS HL7 TO HL9, HL12 TO HL14, HL39 TO HL40, HL40 TO HL60, HL19 TO HL55. OMIT JUMPERS W905, W909, W900, W907.
- FOR PUBLIC ADDRESS OPTION, ADD JUMPERS HL60 TO HL48. HL3 TO HL4. HL8 TO HL9. HL12 TO HL14. OMIT JUMPERS \$902. \$904. \$904. \$908 MIC WITHOUT PREAMP REQUIRES HL61 TO HL62 JUMPER AND DELETE \$905.
- A FOR CHANNEL MEMORY (200 MA MAXIMUM CONTINOUS BATTERY DRAIN) WHEN USING UV ERASABLE U801 (8749) ADD INSULATED JUMPER HL63 TO HL64 AND OMIT W801.
- A FOR IGNITION SWITCH CONTROL, REMOVE JUMPER #901.
- FOR SPEAKER MUTE FUNCTION WITH THE UNIVERAL TONE CABLE OPTION WIHHOUT PA OPTION, OMIT JUMPER 4903, ADD JUMPER HL5 TO HL6 (NOT COMPATIBLE WITH INTERNAL/EXTERNAL SPEAKER). WITH PA OPTION, OMIT 4903 ONLY.
- FOR EXTERNAL SPEAKER OPTION, REMOVE JUMPER \$903 TO DISABLE THE INTERNAL SPEAKER.
- A CUT OUT W301, W302 AND W802 FOR UHF.
- A PRESENT FOR UNITS WITHOUT MULTI-FREG DISPLAY.
- A PART OF KIT PL194701522.
- PWB HAS PROVISION FOR MOUNTING COMPONENTS SHOWN DASHED.
- 11." DENOTES CHIP COMPONENTS (EXAMPLE R1"), WHICH ARE LOCATED ON SOLDER SIDE OF PWB.
- 12. DENOTES A- COMMON TO CHASSIS.
- FOR PHOENIX INTERNATIONAL, ADD JUMPERS HL24
  TO HL60, HL40 TO HL39, HL4 TO R302, HL14
  TO HL48. REMOVE W905, D815 AND C713.
- THE FOLLOWING JUMPERS ARE IMPLEMETED USING ONE OHM RESISTORS.W301.W302, W701.W801.W802.W904.W905.W906.W907, W908.W909.W910 AND W911.CLIP BOTH LEADS TO REMOVE JUMPER.
- THE FOLLOWING JUMPERS ARE IMPLEMENTED USING ZERO OHM "RESISTORS". W901, W902, AND W903.CLIP BOTH LEADS TO REMOVE JUMPER.
- FOR CHANNEL MEMORY (15 MA CONTINUOUS BATTERY DRAIN) ONLY WITH MASKED VERSION (8049) OF U801 CONNECT A902.A903-J4 TO J810 AND A902.A903-J3 TO J811 AND REMOVE W911.
- FOR INTERNAL/EXTERNAL SPEAKER OPTION
  WITH SWITCH (EXTERNAL TO RADIO) DELETE
  W903 AND ADD JUMPER HL5 TO HL6.
- WHEN T99 OPTION OR PUBLIC ADDRESS OPTION ARE PRESENT WITH MULTI-FREQ DISPLAY, REMOVE R911 AND R8.

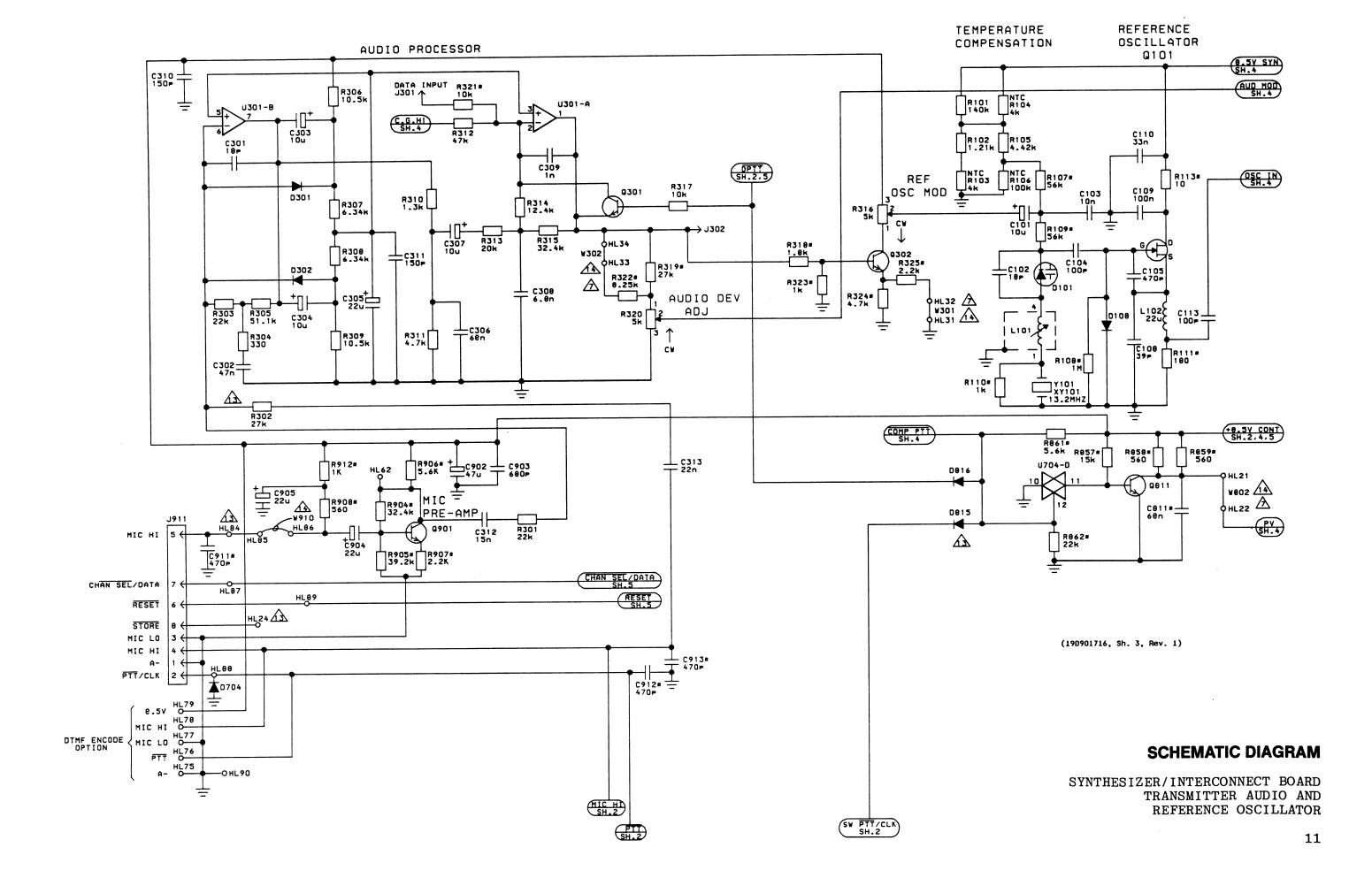
# SCHEMATIC DIAGRAM

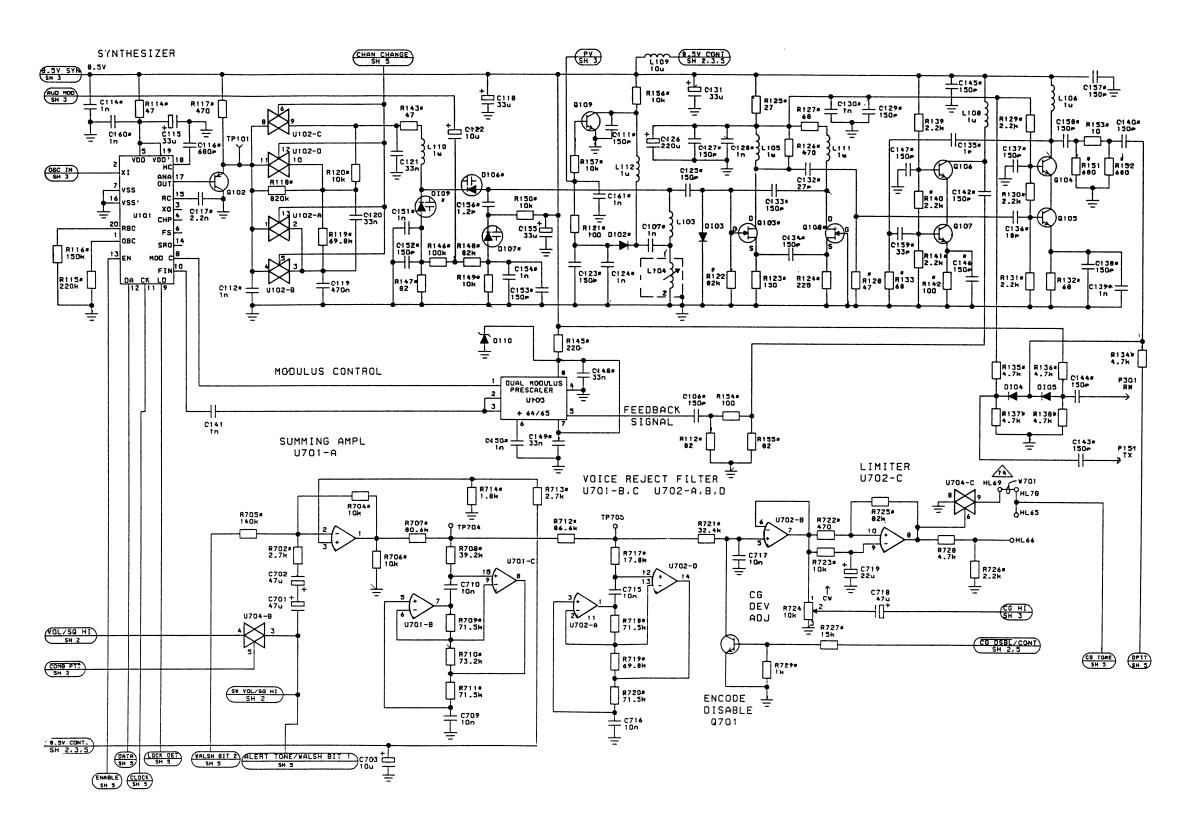


# **SCHEMATIC DIAGRAM**

(190901716, Sh. 2, Rev. 0)

SYNTHESIZER/INTERCONNECTION DIAGRAM INTERFACE AND CHANNEL GUARD FILTER

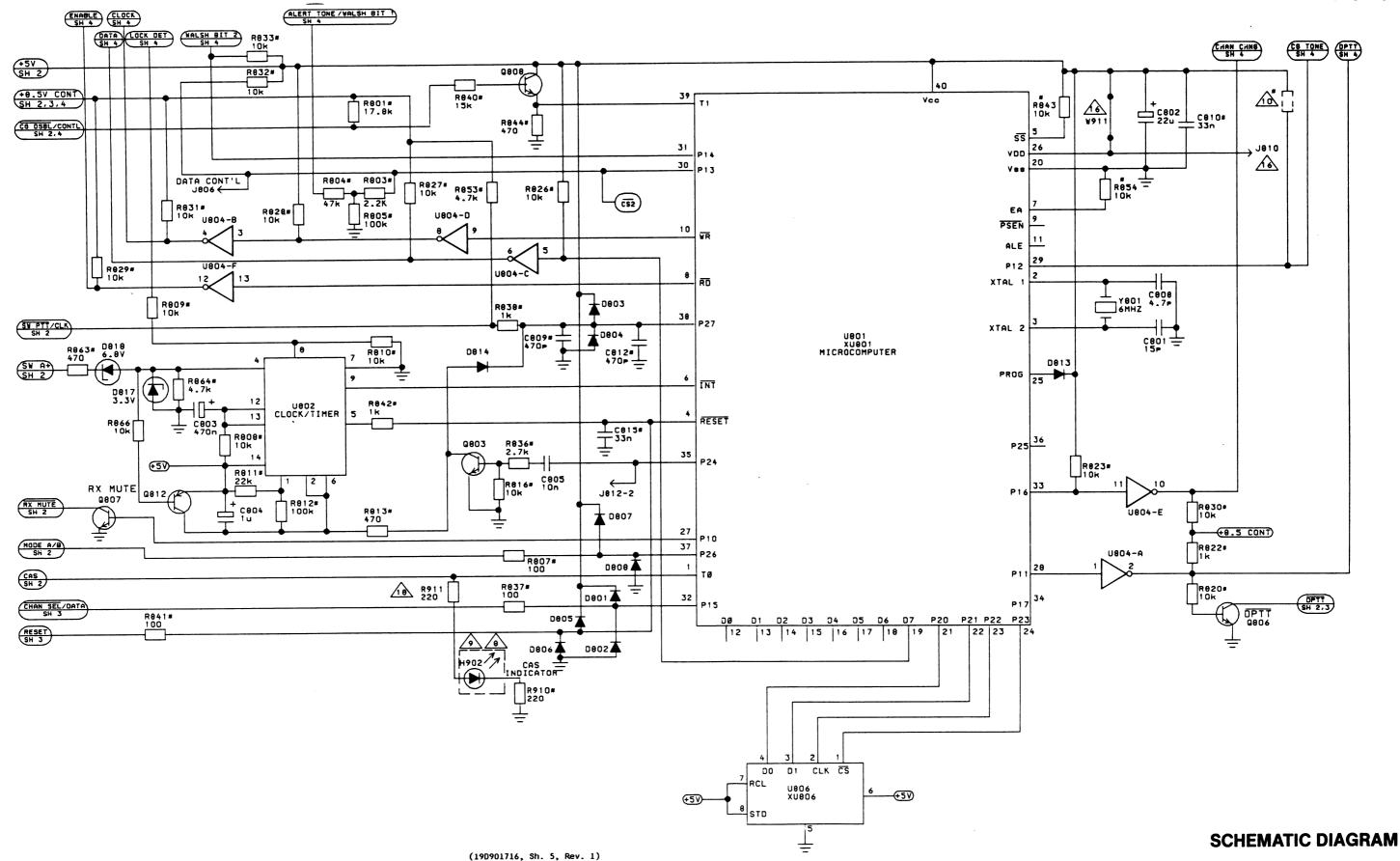




# **SCHEMATIC DIAGRAM**

(19D901716, Sh. 4, Rev. 2)

SYNTHESIZER/INTERCONNECT BOARD FREQUENCY SYNTHESIZER AND CHANNEL GUARD



SYNTHESIZER/INTERCONNECT BOARD SYSTEM CONTROL

# PARTS LIST

WIDEBAND SYNTHESIZER/INTERCONNECT BOARD 19D900961G2 150-174 HRZ (TIN CONTACTS) 19D900961G5 150-174 (GOLD CONTACTS) ISSUE 2

Note: When changing boards, care should be taken to assure boards with gold contacts are not interchanged with boards having tin contacts.

SYMBOL	GE PART NO.	DESCRIPTION
		SYNTHESI ZER
C101	19A703314P10	Electrolytic: 10 uF -10+50% tol, 50 VDCW; sim to Panasonic LS Series.
C102	19A700235P16	Ceramic: 18 pF + or -5%, 50 VDCW.
C103	T644ACP310K	Polyester: .010 uF + or -10%, 50 VDCW.
C104	19A700235P25	Ceramic: 100 pF + or -5%, 50 VDCW.
C105	5490008P43	Silver mica: 470 pF + or - 5%, 300 VDCW, sim. to Electro Motive Type DM-15.
C106	19A702061P65	Ceramic: 150 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/ $^{\circ}$ C.
C107	19A702061P99	Ceramic: 1000 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/`C.
C108	19A700235P20	Ceramic: 39 pF + or -5%, 50 VDCW.
C109	19A702250P113	Polyester: 0.1 uF + or -10%, 50 VDCW.
C110	T644ACP333K	Polyester: .033 uF + or -10%, 50 VDCW.
c111	19A702061P65	Ceramic: 150 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/ C.
C112	19A702061P99	Ceramic: 1000 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/°C.
C113	19A700235P25	Ceramic: 100 pF + or -5%, 50 VDCW.
C114	19A702061P99	Ceramic: 1000 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/°C.
C115	19A703314P3	Electrolytic: 33 uP -10+50% tol, 15 VDCW; sim to Panasonic LS Series.
C116	19A702061P95	Ceramic: 680 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/'C.
C117	19A702052P7	Ceramic: 2200 pF + or - 10%, 50 VDCW.
C118	19A703314P3	Electrolytic: 33 uP -10+50% tol, 15 VDCW; sim to Panasonic LS Series.
C119	19A700004P6	Metallized polyester: 0.47 uF + or -10%, 63 VDCW.
Cl20 and	T644ACP333K	Polyester: .033 uF + or -10%, 50 VDCW.
C121		
C122	19A703314P10	Electrolytic: 10 uP -10+50% to1, 50 VDCW; sim to Panasonic LS Series.
C123	19A702061P65	Ceramic: 150 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/\C.
C124	19A702061P99	Ceramic: 1000 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/`C.
C125	19A702061P65	Ceramic: 150 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/`C.
C126	19A134730P2	Electrolytic: 220 uF +100 -10%, 25 VDCW.
C127	19A702061P65	Ceramic: 150 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/C.
C128	19A702061P99	Ceramic: 1000 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/C.
C129	19A702061P65	Ceramic: 150 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/C.
C130	19A702061P99	Ceramic: 1000 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/`C.
C131	19A703314P3	Electrolytic: 33 uF -10+50% tol, 15 VDCW; sim to Panasonic LS Series.
C132	19A702061P33	Ceramic: 27 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/°C.
C133 and	19A702061P65	Ceramic: 150 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/`C.
C134	19A702061P901	Ceramic: l pF + or -0.25 pF, 50 VDCW, temp coe! 0 + or -250 PPM/`C.
		V . VL -430 FER/ C.

SYMBOL	GE PART NO.	DESCRIPTION	SYMB
C1 36	19A702061P25	Ceramic: 18 pF + or -5%, 50 VDCW, temp coef 0 +	Q102
C137	19A702061P65	or -30 PPM/C.  Ceramic: 150 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/C.	Q103
and C138 C139	19A702061P99	Ceramic: 1000 pF + or -5%, 50 VDCW, temp coef 0	thru Q107
C140	19A702061P65	+ or -30 PPM/°C.	Q108 Q109
		+ or -30 PPM/`C.	
C141 C142	T644ACP210K 19A702061P65	Polyester: .0010 uF + or -10%, 50 VDCW.	R101
thru C147		Ceramic: 150 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/`C.	R102
C148 and C149	19A702052P20	Ceramic: 0.033 uF + or - 10%, 50 VDCW.	R103 and R104
C150 and C151	19A702061P99	Ceramic: 1000 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/`C.	R105
C152 and C153	19A702061P65	Ceramic: 150 pP + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/`C.	R107
C154	19A702061P99	Ceramic: 1000 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/°C.	R109
C155	19A703314P3	Electrolytic: 33 uF -10+50% tol, 15 VDCW; sim to Panasonic LS Series.	R111
C156	19A702236P5	Ceramic: 0.9 pF + or1 pF, 50 VDCW, 0 + or -30 PPM/'C.	R112
C157 and C158	19A702061P65	Ceramic: 150 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/'C.	R114
C159	19A702061P37	Ceramic: 33 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/'C.	R116
C160 and C161	19A702061P99	Ceramic: 1000 pF + or -5%, 50 VDCW, temp coef 0 + or -30 PPM/'C.	R116 R117 R118
		DIODES	1
D101	19A700073P1	Silicon; sim to BB409.	R119
D102	19A702525P2	Silicon.	R120
D103	19A700047P2	Silicon, 100 mW, continuous dissipation; sim to DO-15.	R121
D104 and D105	19A116925P1	Silicon.	R123
D106 and D107	19A7G0085P2	Silicon; sim to MMBV109.	R125
D108	19A700028P1	Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type iN4148.	R127
D109	19A700085P2	Silicon; sim to MMBV109.	R128
D110	19A700025P6	Silicon, zener: 400 mW max; sim to B2X55-C5Vl.	R129 thru R131
			R132
L101	19A703311P3	Coil, RF: sim to TOKO American KRNA-K6571BA.	and R133
L102	19A700024P29	Coil, RF: 22 uH + or - 10%.	R134
L103	19B800891P2 19B800962P111	Coil, RF Choke: sim to Paul Smith SK-890-1.	R1 38
L104 L105	H343CLP10922	Coil, RF, variable: sim to Paul Smith SK-767-1.  Coil, RF: 1.0 uH + or -10%.	R139 thru
and L106	134368210922	coll, kr: 1.0 un + 01 -100.	R141
L108	H343CLP10922	Coil, RF: 1.0 uH + or -10%.	R142
L109	H343CLP10022	Coil, Fixed: 10 uH + or - 10%.	R143
L110 thru	H343CLP10922	Coil, RF: 1.0 uH + or -10%.	R145
L112			R147
			R148
P151	19A701785P3	Contact, electrical. (Used in G2).	R149
P151	19A701785P13	Contact, electrical. (Used in G5).	R150
2101	19A700060P3	N-Type, field effect; sim to J310.	R151 and R152
Q101	19A700060P3	N-Type, field effect; sim to J310.	R

SYMBOL	GE PART NO.	DESCRIPTION
Q102	19A700022P2	Silicon, PNP: sim to 2N3906.
Q103	19A702524P2	N-Type, field effect; sim to MMBFU310.
Q104	19A701808P2	Silicon, NPN; sim to MPS 6595.
thru Q107		
Q108	19A702524P2	N-Type, field effect; sim to MMBFU310.
Q109	19A700023P2	Silicon, NPN: sim to 2N3904.
R101	19A702931P415	Metal film: 140K ohms + or -1%, 200 VDCW, 1/8 w.
R102	19A701250P209	Metal film: 1.21K ohms + or -1%, 1/4 w.
R103 and	19A702161P1	Thermistor: 3300 ohms + or -5%, sim to Philips 2322-642-12332.
R104		
R105	19A701250P263	Metal film: 4.42K ohms + or -1%, 1/4 w.
R106	19A702161P2	Composition: 12K ohms + or -5%, 1/4 w.
R107	19B800607P563	Metal film: 56K ohms + or - 5%, 200 VDCW, 1/8 w.
R108	19B800607P105	Metal film: 1M ohms + or - 5%, 200 VDCW, 1/8 w.
R109	198800607P563	Metal film: 56K ohms + or - 5%, 200 VDCW, 1/8 w.
R110	19B800607P102	Metal film: 1K ohms + or - 5%, 200 VDCW, 1/8 w.
R111 R112	19B800607P181 19B800607P820	Metal film: 180 ohms + or - 5%, 200 VDCW, 1/8 w.
		Metal film: 82 ohms + or - 5%, 200 VDCW, 1/8 w.
R113 R114	19B800607P100 19B800607P470	Metal film: 10 ohms + or -5%, 200 VDCW, 1/8 w.
R115	198800607P470	Metal film: 47 ohms + or - 5%, 200 VDCW, 1/8 w.
K113	198600607224	Metal film: 220K ohms + or - 5%, 200 VDCW, 1/8 W.
R116	19B800607P154	Metal film: 150K ohms + or -5%, 200 VDCW, 1/8 w.
R117	19B800607P471	Metal film: 470 ohms + or - 5%, 200 VDCW, 1/8 w.
R118	198800607P824	Metal film: 820K ohms + or - 5%, 200 VDCW, 1/8
R119	19A702931P382	Metal film: 69.8K ohms + or -1%, 200 VDCW, 1/8
R120	19B800607P103	Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 w.
R121	19B800607P101	Metal film: 100 ohms + or - 5%, 200 VDCW, 1/8 w.
R122	19B800607P823	Metal film: 82K ohms + or -5%, 200 VDCW, 1/8 w.
R123	19B800607P151	Metal film: 150 ohms + or - 5%, 200 VDCW, 1/8 w.
R124	19B800607P221	Metal film: 220 ohms + or - 5%, 200 VDCW, 1/8 w.
R125	19B800607P270	Metal film: 27 ohms + or - 5%, 200 VDCW, 1/8 w.
R126	19B800607P471	Metal film: 470 ohms + or - 5%, 200 VDCW, 1/8 w.
R127	19B800607P680	Metal film: 68 ohms + or - 5%, 200 VDCW, 1/8 w.
R128	198800607P470	Metal film: 47 ohms + or - 5%, 200 VDCW, 1/8 w.
R129 thru	19B800607P222	Metal film: 2.2K ohms + or - 5%, 200 VDCW, 1/8
R131		
R132 and R133	19B800607P680	Metal film: 68 ohms + or - 5%, 200 VDCW, 1/8 w.
R134 thru R138	19B800607P472	Metal film: 4.7K ohms + or - 5%, 200 VDCW, 1/8
R1 39	19B800607P222	Metal film: 2.2K ohms + or - 5%, 200 VDCW, 1/8
thru R141		w.
R142	19B800607P101	Metal film: 100 ohms + or - 5%, 200 VDCW, 1/8 w.
R143	19B800607P470	Metal film: 47 ohms + or - 5%, 200 VDCW, 1/8 w.
R145	19B800607P221	Metal film: 220 ohms + or - 5%, 200 VDCW, 1/8 w.
R146	19B800607P104	Metal film: 100K ohms + or - 5%, 200 VDCW, 1/8
R147	19B800607P820	w. Metal film: 82 ohms + or - 5%, 200 VDCW, 1/8 w.
R148	19B800607P823	Metal film: 82K ohms + or -5%, 200 VDCW, 1/8 w.
R149	19B800607P823	Metal film: 15K ohms + or - 5%, 200 VDCW, 1/8 w.
R150	19B800607P103	Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 w.
R151	19B800607P681	Metal film: 680 ohms + or - 5%, 200 VDCW, 1/8 w.

14

LBI-31584

SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
								22 up 10.500 to 1 25 UDCW. gim			
R153	19B800607P100	Metal film: 10 ohms + or -5%, 200 VDCW, 1/8 w.	R307 and	19A701250P278	Metal film: 6.34K ohms + or -1%, 1/4 w.	C719	19A703314P5	Electrolytic: 22 uF -10+50% tol, 25 VDCW; sim to Panasonic LS Series.	тР703		Part of Printed wire board.
R154	19B800607P101	Metal film: 100 ohms + or - 5%, 200 VDCW, 1/8 w.	R308						thru TP705		
R155	19B800607P820	Metal film: 82 ohms + or - 5%, 200 VDCW, 1/8 w.	R309	19A701250P303	Metal film: 10.5K ohms + or -1%, 1/4 w.  Deposited carbon: 1.3K ohms + or - 5%, 1/4 w.	D702	19A700028Pl	Silicon, fast recovery: fwd current 75 mA, 75			
R156 and	19B800607P103	Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 w.	R310 R311	19A143400P38 H212CRP247C	Deposited carbon: 1.3k ohms + or -5%, 1/4 w.	thru D704		PIV; sim to Type lN4148.	U701	19A701789P1	Linear, Low Power OP AMP; sim to LM324N.
R157			R312	H212CRP347C	Deposited carbon: 47K ohms + or -5%, 1/4 w.				and U702	198/01/0921	Zincut, Zon tonet of thin, John to Lincoln
			R313	19A701250P330	Metal film: 20K ohms + or -1%, 1/4 w.			RESISTORS	U703	19A700086P2	DUAL OP AMP; sim to Type 1458.
TP101	19A703248P2	Contact, electrical.	R314	19A701250P310	Metal film: 12.4K ohms + or -1%, 1/4 w.	R702	19B800607P272	Metal film: 2.7K ohms + or - 5%, 200 VDCW, 1/8 w.	U704	19A700029P44	Digital: BILATERAL SWITCH.
			R315	19A701250P350	Metal film: 32.4K ohms + or -1%, 1/4 w.	R704	19B800607P103	Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 w.	""		
		INTEGRATED CIRCUITS	R316	19B800784P106	Variable: 5K ohms + or -20%, 1/2 w.	R705	19A702931P415	Metal film: 140K ohms + or -1%, 200 VDCW, 1/8 w.	1		
U101	19B800902P4	Synthesizer: CMOS Serial Input.	R317	H212CRP310C	Deposited carbon: 10K ohms + or - 5%, 1/4 w.	R706	19B800607P103	Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 w.	W701	H212CRP910C	Deposited carbon: 1 ohm + or -5%, 1/4 w.
U102	19A700029P44	Digital: BILATERAL SWITCH.	R318	19B800607P182	Metal film: 1.8K ohms + or - 5%, 200 VDCW, 1/8	R707	19A702931P388	Metal film: 80.6K ohms + or -1%, 200 VDCW, 1/8			
U103	19A703091P1	DIVIDER.			w.	7700	1017020210250	w. Metal film: 39.2K ohms + or -1%, 200 VDCW, 1/8			MICRO-COMPUTER CONTROL
			R319	19B800607P273	Metal film: 27K ohms + or - 5%, 200 VDCW, 1/8 w.	R708	19A702931P358	W			
XY101	19A702742P1	Crystal socket.	R320	19B800784P106	Variable: 5K ohms + or -20%, 1/2 w.	R709	19A702931P383	Metal film: 71.5K ohms + or -1%, 200 VDCW, 1/8	C801	19A700235P15	Ceramic: 15 pF + or - 5%, 50 VDCW.
			R321	19B800607P103	Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 w.  Metal film: 8250 ohms + or -1%, 200 VDCW, 1/8 w.	R710	19A702931P384	Metal film: 73.2K ohms + or -1%, 200 VDCW, 1/8	C802	19A703314P5	Electrolytic: 22 uF -10+50% tol, 25 VDCW; sim
Y101	19A703049G1	Quartz: 13.200 MHz.	R322	19A702931P289	Metal film: 1K ohms + or - 5%, 200 VDCW, 1/8 w.	R/10	1987029311304	w.		10170152402	to Panasonic LS Series.  Tantalum: 0.47 uF + or - 20%, 35 VDCW.
1101	25 000 1500		R323	19B800607P102	Metal film: 4.7K ohms + or - 5%, 200 VDCW, 1/8	R711	19A702931P383	Metal film: 71.5K ohms + or -1%, 200 VDCW, 1/8	C803	19A701534P3 19A701534P4	Tantalum: 1 uF + or - 20%, 35 VDCW.
		AUDIO PROCESSOR	R324	19B800607P472	W. W. 111m: 4.7% Ohms + Ot - 54, 200 VECW, 170	R712	19A702931P391	Metal film: 86.6K ohms + or -1%, 200 VDCW, 1/8	C804	T644ACP310K	Polyester: .010 uF + or -10%, 50 VDCW.
			R325	19B800607P222	Metal film: 2.2K ohms + or - 5%, 200 VDCW, 1/8			w.	C805	19A703314P4	Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim
		CAPACITORS			**	R713	19B800607P272	Metal film: 2.7K ohms + or - 5%, 200 VDCW, 1/8	C806	194/0331424	to Panasonic LS Series.
C301	19A700235P16	Ceramic: 18 pF + or -5%, 50 VDCW.	1		INTEGRATED CIRCUITS	R714	19B800607P182	Metal film: 1.8K ohms + or - 5%, 200 VDCW, 1/8	C807	19A702052P3	Ceramic: 470 pF + or - 10%, 50 VDCW.
C302	19A702250P211	Polyester: 0.47 uF + or -5%, 50 VDCW.	U301	19A700086P4	Operation Amplifier, Dual OP AMP; sim to 4558 Type.			w.	C808	19A700235P9	Ceramic: 4.7 pF + or -0.25 pF, 50 VDCW, temp coef N150 PPM/ C.
C303 and	19A7033-4P10	Electrolytic: 10 uF -10+50% tol, 50 VDCW; sim to Panasonic LS Series.			1.72	R715	19B800607P823	Metal film: 82K ohms + or -5%, 200 VDCW, 1/8 w.	C809	19A702052P3	Ceramic: 470 pF + or - 10%, 50 VDCW.
C304						R717	19A702931P325	Metal film: 17.8K ohms + or -1%, 200 VDCW, 1/8 w.	C810	19A702052P20	Ceramic: 0.033 uP + or - 10%, 50 VDCW.
C305	19A701534P8	Tantalum: 22 uF + or -20%, 16 VDCW.	W301 and	H212CRP910C	Deposited carbon: 1 ohm + or -5%, 1/4 w.	R718	19A702931P383	Metal film: 71.5K ohms + or -1%, 200 VDCW, 1/8	C811	19A702052P24	Ceramic: 0.068 uF + or - 10%, 50 VDCW.
C306	19A702250P212	Polyester: 0.68 uF + or -5%, 50 VDCW.	W302					w.	C812	19A702052P3	Ceramic: 470 pF + or - 10%, 50 VDCW.
C307	19A703314P10	Electrolytic: 10 uF -10+50% to1, 50 VDCW; sim to Panasonic LS Series.			1	R719	19A702931P382	Metal film: 69.8K ohms + or -1%, 200 VDCW, 1/8 w.	C815	19A702052P20	Ceramic: 0.033 uF + or - 10%, 50 VDCW.
C308	T644ACP268J	Polyester: .0068 uF + or -5%, 50 VDCW.			CHANNEL GUARD	R720	19A702931P383	Metal film: 71.5K ohms + or -1%, 200 VDCW, 1/8			
C309	T644ACP210J	Polyester: .0010 uF + or -5%, 50 VDCW.					1017000110150	W.  Metal film: 32.4K ohms + or -1%, 200 VDCW, 1/8			DIODES
C310	19A700233P2	Ceramic, disc: 100 pF + or -20%, 50 VDCW.	C701	19A703314P4	Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim	R721	19A702931P350	W. 32.4k Onlins + Ot -16, 200 VDCW, 1/0	D801 thru	19A700028P1	Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.
and C311					to Panasonic LS Series.	R722	19B800607P471	Metal film: 470 ohms + or - 5%, 200 VDCW, 1/8 w.	D808		6.2
C312	T644ACP315K	Polyester: .015 uF + or -10%, 50 VDCW.				R723	19B800607P103	Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 w.	D813 thru	19A700028P1	Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type 1N4148.
C313	T644ACP322K	Polyester: .022 uF + or -10%, 50 VDCW.	D701	19A700028PI	Silicon, fast recovery: fwd current 75 mA, 75	R724	19B800784P108	Variable: 10K ohms + or -20%, 1/2 w.	D816		Silicon, zener: 400 mW max; sim to BZX55-C5Vl.
	1				PIV; sim to Type lN4148.	R725	19B800607P823	Metal film: 82K ohms + or -5%, 200 VDCW, 1/8 w.	D817	19A700025P6	Silicon, zener: 400 mW max; sim to BZX55-C3V3.
D301	19A700028P1	Silicon, fast recovery: fwd current 75 mA, 75				R726	19B800607P222	Metal film: 2.2K ohms + or - 5%, 200 VDCW, 1/8	D818	19A700025P3	Silicon, fast recovery: fwd current 75 mA, 75
and D302	15, 10.02.01	PIV; sim to Type 1N4148.	Q701	19A700023P2	Silicon, NPN: sim to 2N3904.	R727	19B800607P153	Metal film: 15K ohms + or - 5%, 200 VDCW, 1/8 w.	D819	19A700028P1	PIV; sim to Type 1N4148.
5302			<b>!</b>			R728	H212CRP247C	Deposited carbon: 4.7K ohms + or -5%, 1/4 w.			
	1		C702	19A703314P4	Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim	R729	19B800607P102	Metal film: 1K ohms + or - 5%, 200 VDCW, 1/8 w.	J806		Connector. Includes:
J301 and	19A703248P2	Contact, electrical.	6,02	150,70331414	to Panasonic LS Series.	R736	19B800607P223	Metal film: 22K ohms + or - 5%, 200 VDCW, 1/8 w.	1 3000	19A703248P5	Contact, electrical.
J302			C703	19A703314P10	Electrolytic: 10 uF -10+50% to1, 50 VDCW; sim to Panasonic LS Series.	R737	19B800607P153	Metal film: 15K ohms + or - 5%, 200 VDCW, 1/8 w.		19A703248P17	Contact, electrical.
			C704	T644ACP368J	Polyester: .068 uF + or -5%, 50 VDCW.	R738	19A702931P321	Metal film: 16.2K ohms + or -1%, 200 VDCW, 1/8	J810	1 33	Connector. Includes:
P301	19A701785P3	Contact, electrical. (Used in G2).	C705	T644ACP333J	Polyester: .033 uF + or -5%, 50 VDCW.		i.	w.	thru J812		
P301	19A701785P13	Contact, electrical. (Used in G5).	C706	19A701534P2	Tantalum: 0.22 uF + or -20%, 35 VDCW.	R739	19B800607P223	Metal film: 22K ohms + or - 5%, 200 VDCW, 1/8 w.		19A703248P5	Contact, electrical.
			C707	T644ACP333J	Polyester: .033 uF + or -5%, 50 VDCW.	R740	19A702931P305	Metal film: 11K ohms + or -1%, 200 VDCW, 1/8 w.		19A703248P17	Contact, electrical.
			C708	T644ACP368J	Polyester: .068 uF + or -5%, 50 VDCW.	R741	19A702931P322	Metal film: 16.5K ohms + or -1%, 200 VDCW, 1/8 w.		,	
Q301 and	19A700023P2	Silicon, NPN: sim to 2N3904.	C709	T644ACP310J	Polyester: .010 uF + or -5%, 50 VDCW.	R742	19B800607P473	Metal film: 47K ohms + or - 5%, 200 VDCW, 1/8 w.	Q803	19A700023P2	Silicon, NPN: sim to 2N3904.
Q302			and C710	1		R743	19A702931P284	Metal film: 7320 ohms + or -1%, 200 VDCW, 1/8 w.	Q806	19A700023P2	Silicon, NPN: sim to 2N3904.
		RESISTORS	L C/11	T644ACP333J	Polyester: .033 uF + or -5%, 50 VDCW.	R744	19A702931P317	Metal film: 14.7K ohms + or -1%, 200 VDCW, 1/8	thru Q808	1	
R301	H212CRP322C	Deposited carbon: 22K ohms + or -5%, 1/4 w.	and C712			R745	19A702931P151	Wetal film: 332 ohms + or -1%, 250 VDCW, 1/8 w.	Q811	19A700023P2	Silicon, NPN: sim to 2N3904.
	H212CRP327C	Deposited carbon: 27K ohms + or -5%, 1/4 w.	C713	19A702250P113	Polyester: 0.1 uF + or -10%, 50 VDCW.	R745	19A702931P131	Metal film: 12.1K ohms + or -1%, 200 VDCW, 1/8	Q812	19A700022P2	Silicon, PNP: sim to 2N3906.
R302	H212CRP322C	Deposited carbon: 22K ohms + or -5%, 1/4 w.	C715	T644ACP310J	Polyester: .010 uF + or -5%, 50 VDCW.	K/40	198,029311309	W.			RESISTORS
R302 R303		1 220 obms + or -59 1/4 W.	thru	1	1	R747	19A702931P289	Metal film: 8250 ohms + or -1%, 200 VDCW, 1/8 w.		1	
	H212CRP133C	Deposited carbon: 330 ohms + or -5%, 1/4 w.	C717	1	I						Motal films 17 07 ohmo ± or =19 700 Uncw 17
R303	i i	Metal film: 51.1K ohms + or -1%, 1/4 w.	C717	19A703314P4	Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim	R748	19A702931P358	Metal film: 39.2K ohms + or -1%, 200 VDCW, 1/8	R801	19A702931P325	Metal film: 17.8K ohms + or -1%, 200 VDCW, 1/w.
R303 R304	H212CRP133C		11	19A703314P4	Electrolytic: 47 uF -10+50% tol, 16 VDCW; sim to Panasonic LS Series.	R748	19A702931P358	Metal film: 39.2K ohms + or -1%, 200 VDCW, 1/8 w.	R801	19A702931P325	Metal film: 17.8K ohms + or -1%, 200 VDCW, 1/8 w.
R303 R304 R305	H212CRP133C 19A701250P369	Metal film: 51.1K ohms + or -1%, 1/4 w.	11	19A703314P4		R748	19A702931P358	Metal film: 39.2K ohms + or -1%, 200 VDCW, 1/8 W.	R801	19A702931P325	Metal film: 17.8K ohms + or -1%, 200 VDCW, 1/w.

LBI-31584

R803 19880607P222 Metal film: 2.2K ohms + or - 5%, 200 VDCW, 1/8 v. R804 19880607P473 Metal film: 47K ohms + or - 5%, 200 VDCW, 1/8 v. R805 19880607P101 Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 v. C901 19A702251B3 Electrolytic: 220 ur, -10+50% tol, 25 VDCW. R816 198800607P103 Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 v. C904 19A702031P4 Electrolytic: 220 ur, -10+50% tol, 25 VDCW. R816 198800607P104 Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 v. C904 19A702031P6 Electrolytic: 22 ur, -10+50% tol, 25 VDCW. R816 198800607P104 Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 v. C904 19A702031P6 Electrolytic: 22 ur, -10+50% tol, 25 VDCW, 1/8 v. C905 19A702031P6 Electrolytic: 22 ur, -10+50% tol, 25 VDCW, 1/8 v. C906 19A702031P6 Electrolytic: 22 ur, -10+50% tol, 25 VDCW, 1/8 v. C906 19A702031P6 Electrolytic: 22 ur, -10+50% tol, 25 VDCW, 1/8 v. C906 19A702031P6 Electrolytic: 22 ur, -10+50% tol, 25 VDCW, 1/8 v. C906 19A702031P6 Electrolytic: 22 ur, -10+50% tol, 25 VDCW, temp coef 0 tol, 25 VDCW, temp coef 0 tol, 25 VDCW, temp coef 0 tol, 25 VDCW, 1/8 v. C906 19A702052P3 Ceramic: 470 pf + or - 10%, 50 VDCW. Lemp coef 0 tol, 25 VDCW, temp coef 0 tol, 25 VDCW, 1/8 v. C916 19B800607P102 Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 v. C916 19B800607P103 Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 v. C916 19B800607P103 Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 v. C916 19B800607P103 Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 v. C916 19B800607P103 Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 v. C916 19B800607P103 Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 v. C916 19B800607P103 Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 v. C916 19B800607P103 Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 v. C916 19B800607P103 Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 v. C916 19B800607P103 Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 v. C916 19B800607P103 Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 v. C916 19B800607P103 Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 v. C916 19B800607P103 Metal film: 10K ohms + or - 5%	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
March   Marc				<b> </b>					5255KII 115K
1985   1986   1987	R803	19B800607P222	Metal film: 2.2K ohms + or - 5%, 200 VDCW, 1/8	V801	19270251162	1	R904	19A702931P350	
1987   1987-1997	R804	19B800607P473		1001	ĺ	1	R905	19A702931P358	Metal film: 39.2K ohms + or -1%, 200 VDCW, 1/8
Section   Column	R805	19B800607P104	l i				R906	1988006079562	We Maral film: 5 6K ohmo + or - 59 200 Upou 1/0
1000000000000000000000000000000000000	R807	19B800607P101	W.  Metal film: 100 ohms + or - 5%, 200 VDCW 1/8	C901	19270122503	1			
Wilder   W		19B800607P103	1				R907	19B800607P222	Metal film: 2.2K ohms + or - 5%, 200 VDCW, 1/8 w.
100-100-1007-100   100-100-100-100-100-100-100-100-100-100						to Panasonic LS Series.	R908	19B800607P561	Metal film: 560 ohms + or - 5%, 200 VDCW, 1/8 w.
	R811	19B800607P223	Metal film: 22K ohms + or - 5%, 200 VDCW, 1/8 w.			1	R909	19B800607P471	Metal film: 470 ohms + or - 5%, 200 VDCW, 1/8 w.
March   Marc	R812	19B800607P104	Metal film: 100K ohms + or - 5%, 200 VDCW, 1/8	and	194/0331425	Electrolytic: 22 uF -10+50% to1, 25 VDCW; sim to Panasonic LS Series.	1		Metal film: 220 ohms + or - 5%, 200 VDCW, 1/8 w.
1981-1001-1001-1001-1001-1001-1001-1001-	R813	19B800607P471	Metal film: 470 ohms + or - 5%, 200 VDCW, 1/8 w.	1	19A702061P99	Ceramic: 1000 pF + or -5%. 50 VDCW. temp coef 0			
1300000077101   130000077101   130000077101   130000077101   130000077101   130000077101   1300000	R816	19B800607P103	1			+ of -30 PPM/ C.			<u> </u>
\$1   \$1   \$1   \$1   \$1   \$1   \$1   \$1	R820	19B800607P103	Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 w.	thru	19A702052P3	Ceramic: 470 pF + or - 10%, 50 VDCW.	1		, ,
				1	19A702061P99	Ceramic: 1000 pp + or -5% 50 VDCW			w.
1985   198050077777				and		+ or -30 PPM/C.			
1300-2007-201   No. 12   1300-2007-201   No. 12   1300-201   130	thru	198800607P103	Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 w.					19A700184P1	Jumper.
## 17		19B800607P272	Metal film: 2.7K ohms + or - 5% 200 VDCW 1/0	D901	T324ADD1041	1	W903		
### 138600072123 ### 17 15 0 the note of months of month			".	and	13244011041	Rectifier, silicon; general purpose.	thru	H212CRP910C	Deposited carbon: 1 ohm + or -5%, 1/4 w.
March   Marc	1						W911		ļ
1980-00079733   Market filter 10 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 11 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 11 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 11 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 11 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 11 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter 12 course or " M. 70 WORM, 1/W w.   1980-0007973   Market filter	1		1			į			MISCELLANEOUS
### 198000071920   Marked files 12 min s for - 51, 200 year, 1/8 v.   ### 198000071920   Marked files 12 min s for - 51, 200 year, 1/8 v.   ### 198000071920   Marked files 12 min s for - 51, 200 year, 1/8 v.   ### 198000071920   Marked files 12 min s for - 51, 200 year, 1/8 v.   ### 198000071920   Marked files 12 min s for - 51, 200 year, 1/8 v.   ### 198000071920   Marked files 12 min s for - 51, 200 year, 1/8 v.   ### 198000071920   Marked files 12 min s for - 51, 200 year, 1/8 v.   ### 198000071920   Marked files 12 min s for - 51, 200 year, 1/8 v.   ### 198000071920   Marked files 12 min s for - 51, 200 year, 1/8 v.   ### 198000071920   Marked files 12 min s for - 51, 200 year, 1/8 v.   ### 198000071920   Marked files 12 min s for - 51, 200 year, 1/8 v.   ### 198000071920   Marked files 12 min s for - 51, 200 year, 1/8 v.   ### 198000071920   Marked files 12 min s for - 51, 200 year, 1/8 v.   ### 198000071920   Marked files 12 min s for - 51, 200 year, 1/8 v.   ### 198000071920   Marked files 12 min s for - 51, 200 year, 1/8 v.   ### 198000071920   Marked files 12 min s for - 51, 200 year, 1/8 v.   ### 198000071920   Marked files 12 min s for - 51, 200 year, 1/8 v.   ### 198000071920   Marked files 12 min s for - 51, 200 year, 1/8 v.   ### 198000071920   Marked files 12 min s for - 51, 200 year, 1/8 v.   ### 198000000071920   Marked files 12 min s for - 51, 200 year, 1/8 v.   ### 198000000000000000000000000000000000000	1 1		1	1		-		19A700068P1	Insulator, bushing. (Part of U803).
March   198806077920			Contact, electrical.	"505	134134334F3	Packard 5082-4955.			i .
1980/000/07/19   Model files 10 do not or - 0 - 39, 20 WORL, 1/8 w.   390	R842	19B800607P102	Metal film: 1K ohms + or - 5%, 200 VDCW, 1/8 w.					19A702364P208	Machine screw: TORX Drive, M2.5 - 0.45 x 8. (Part of U803).
198000077127   Mark film   170 Camba for 1 x y 200   1000x   174   175	R843	19B800607P103	Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 w.	J901	19J706214P4	Connector: 4 contacts rated @ 7 amps; sim to		19B800952P1	Support. (Part of U803).
1980-00791753   Section   1980-00791755	R844	19B800607P471	Metal film: 470 ohms + or - 5%, 200 VDCW, 1/8 w.	.7901	1031166500105	!		19A134717P1	4K PROGRAMMED MEMORY. (Part of U803).
198006079123	R853	19B800607P472		","	1941100599105	Connector: 4 contacts rated @ 7 amps; sim to Molex 09-80-1045. (Used with G5).		19A700033P3	Lockwasher, external tooth: M2.5. (Part of U803).
1981000077137   1981000077137   Metal film: 158 ohms + or - 59, 200 VDCW, 1/8 v.   2794   2	R854	19B800607P103	Metal film: 10K ohms + or - 5%, 200 VDCW, 1/8 w.	J903	19A116659P186	Connector: 7 contacts rated @ 7 amps; sim to Molex 09-80-1075. (Used with G5).		19A700034P3	Hex nut, metric: M2.5 x 0.45. (Part of U803).
1980/06/7942   Metal film: 5.66 chms + or - 54, 200 VDCW, 1/8 v.   1980/06/7942   Metal film: 5.66 chms + or - 54, 200 VDCW, 1/8 v.   1980/06/7942   Metal film: 272 chms + or - 54, 200 VDCW, 1/8 v.   1980/06/7942   Metal film: 4.76 chms + or - 54, 200 VDCW, 1/8 v.   1980/06/7942   Metal film: 4.76 chms + or - 54, 200 VDCW, 1/8 v.   2910   1980/06/7942   Metal film: 4.76 chms + or - 54, 200 VDCW, 1/8 v.   2910   1980/06/7942   Metal film: 4.76 chms + or - 54, 200 VDCW, 1/8 v.   2910   1980/06/7942   Metal film: 4.76 chms + or - 54, 200 VDCW, 1/8 v.   2910   1980/06/7942   Metal film: 4.76 chms + or - 54, 200 VDCW, 1/8 v.   2910   1980/06/7942   Metal film: 4.76 chms + or - 54, 200 VDCW, 1/8 v.   2910   1980/06/7942   Metal film: 4.76 chms + or - 54, 200 VDCW, 1/8 v.   2910   1980/06/7942   Metal film: 4.76 chms + or - 54, 200 VDCW, 1/8 v.   2910   1980/06/7942   Metal film: 5.66 chms + or - 54, 200 VDCW, 1/8 v.   2910   1980/06/7942   Metal film: 5.66 chms + or - 54, 200 VDCW, 1/8 v.   2910   1980/06/7942   Metal film: 5.66 chms + or - 54, 200 VDCW, 1/8 v.   2910   1980/06/7942   Metal film: 5.66 chms + or - 54, 200 VDCW, 1/8 v.   2910   1980/06/7942   Metal film: 5.66 chms + or - 54, 200 VDCW, 1/8 v.   2910   1980/06/7942   Metal film: 5.66 chms + or - 54, 200 VDCW, 1/8 v.   2910   1980/06/7942   Metal film: 5.66 chms + or - 54, 200 VDCW, 1/8 v.   2910   1980/06/7942   Metal film: 5.66 chms + or - 54, 200 VDCW, 1/8 v.   2910   1980/06/7942   Metal film: 5.66 chms + or - 54, 200 VDCW, 1/8 v.   2910   Metal film: 5.66 chms + or - 54, 200 VDCW, 1/8 v.   2910   Metal film: 5.60 chms + or - 54, 200 VDCW, 1/8 v.   2910   Metal film: 5.60 chms + or - 54, 200 VDCW, 1/8 v.   2910   Metal film: 5.60 chms + or - 54, 200 VDCW, 1/8 v.   2910   Metal film: 5.60 chms + or - 54, 200 VDCW, 1/8 v.   2910   Metal film: 5.60 chms + or - 54, 200 VDCW, 1/8 v.   2910   Metal film: 5.60 chms + or - 54, 200 VDCW, 1/8 v.   2910   Metal film: 5.60 chms + or - 54, 200 VDCW, 1/8 v.   2910   Metal film: 5.60 chms + or - 54, 200 VDCW, 1/8	R857	19B800607P153	Metal film: 15K ohms + or - 5%, 200 VDCW, 1/8 w.	J903	19J706214P7	Flat wafer: 7 contacts rated @ 7 amps; sim to		19A701312P3	Flatwasher, metric: No. 2.5MM. (Part of U803).
### 198806677522 ### Metal film: 5.6k ohms + or - 5%, 200 VDCW, 1/8 w.  ### ### ### ### ### ### ### ### ### #	and	19B800607P561	Metal film: 560 ohms + or - 5%, 200 VDCW, 1/8 w.	J904		· ·			
198008079223   Netal film: 228 chms + or - 58, 200 VDCN, 1/8 v.	1	100000070502							
198006079471	K001	1986006072562	Metal film: 5.6K ohms + or - 5%, 200 VDCW, 1/8		19A703248P5	Contact, electrical.			į
Mach   198006077472   Mach   198006077472   Mach   198006077472   Mach   198006077472   Mach   198006077472   Mach   1980060775472   Mach   19800607755472   Mach   19800607					19A703248P17	Contact, electrical.			
Molex 99-75-116.  Molex 99-75-116.  Deposited carboni 10K ohms + or - 5x, 1/4 w.  19311 1931166599183				J910	19A116659P184	Connector, printed wiring, 11 contacts: sim to			
Molecus 09-75-1086.	K864	19880060/P4/2	Metal film: 4.7K ohms + or - 5%, 200 VDCW, 1/8 w.	701,	1011166601100	Molex 09-75-1116.			
19A703244P40	R866	H212CRP310C	Deposited carbon: 10K ohms + or - 5%, 1/4 w.	3911	19A116659P183	Connector, printed wiring, 8 contacts; sim to Molex 09-75-1086.			
U801 19A703244P40 Microcomputer: HMOS, 8-bit, 40 Pin Dip. U802 19A116969P3 Linear, timer: DUAL IN-LINE 14 Pin Dip Package; sin to Signetics SASSON. U804 19B801346G1 Transistor, heat sink assembly. U806 19A704032P1 Digital: HEX INVERTER BUFFER/DRIVER (OPEN COLLECTOR).  U806 19A704032P1 Digital: 16 x 16 bit RAM; sim to XICOR Part No. X2444P.  W801 and w802 Deposited carbon: 1 ohm + or -5%, 1/4 w.  W801 19A700156P5 Socket, integrated circuit: 40 contacts; sim to August 140-AG39D.  XUB06 19A700156P15 Integrated circuit: 8 positions; sim to Burndy  U801 19A700156P15 Integrated circuit: 8 positions; sim to Burndy  U802 19A700156P15 Integrated circuit: 8 positions; sim to Burndy  U803 19A700156P15 Integrated circuit: 8 positions; sim to Burndy  U804 19A700156P15 Integrated circuit: 8 positions; sim to Burndy  U805 19A700156P15 Integrated circuit: 8 positions; sim to Burndy  U806 19A700156P15 Metal film: 560 ohms + or - 5%, 200 VDCW, 1/8 w.				J912	19J706214P4	Connector: 4 contacts rated @ 7 amps; sim to Molex 09-67-1042. (Used with G2)			
U804 19801346cl Transistor, heat sink assembly.  U804 19A116180P33 Digital: HEX INVERTER BUFFER/DRIVER (OPEN COLLECTOR).  U806 19A704032P1 Digital: 16 x 16 bit RAM; sim to XICOR Part No. X2444P.  W801 and w802 19801360P3 Deposited carbon: 1 ohm + or -5%, 1/4 w.  W801 and w802 19A700156P5 Socket, integrated circuit: 40 contacts; sim to August 140-AG39D.  XU806 19A700156P15 Integrated circuit: 8 positions; sim to Burndy DILB 8P-108.  U801 19B801346cl Transistor, heat sink assembly.  J920 20 Connector. Includes:  Contact, electrical.  Contact, ele	U801	19A703244P40	Microcomputer: HMOS, 8-bit, 40 Pin Dip.	J912	19A116659P185	Connector: 4 contacts rated @ 7 amps; sim to			
U803 1980134661 Transistor, heat sink assembly.  U804 19A116180P33 Digital: HEX INVERTER BUFFEr/DRIVER (OPEN COLLECTOR).  U806 19A704032P1 Digital: 16 x 16 bit RAM; sim to XICOR Part No. X2444P.  W801 and w802 M802	U802	19A116968P3	Linear, timer: DUAL IN-LINE 14 Pin Dip Package; sim to Signetics SA556N.	.1920		· ·			
U804 19A116180933 Digital: HEX INVERTER BUFFER/DRIVER (OPEN COLLECTOR).  U806 19A704032P1 Digital: 16 x 16 bit RAM; sim to XICOR Part No. X2444P.  W801 and w802 Peposited carbon: 1 ohm + or -5%, 1/4 w.  W801 19A700156P5 Deposited carbon: 1 ohm + or -5%, 1/4 w.  XU801 19A700156P5 Socket, integrated circuit: 40 contacts; sim to August 340-Ad3990.  XU806 19A700156P15 Integrated circuit: 8 positions; sim to Burndy DILB 8P-108.  R901 19B800607P561 Metal film: 560 ohms + or -5%, 200 VDCW, 1/8 w.	U803	19B801346G1	·	and	ļ	Connector. Includes:			
U806 19A704032P1 Digital: 16 x 16 bit RAM; sim to XICOR Part No. X2444P.  W801 AND	U804	19A116180P33	Digital: HEX INVERTER BUFFER/DRIVER (OPEN		19A703248P5	Contact, electrical.			
W801 and w802	U806	19A704032P1			19A703248P17	Contact, electrical.			
W801 and w802			x2444P.						i
W801 and W802				L901	H343CLP12922	1			
W802		H212CRP910C	Deposited carbon: 1 ohm + or -5%, 1/4 w.						
XU801 19A700156P5 Socket, integrated circuit: 40 contacts; sim to Augat 340-Ac39D.  XU806 19A700156P15 Integrated circuit: 8 positions; sim to Burndy DILB 8P-108.  Q901 19A116774P3 Transistor, NPN: sim to 2N5210.  R901 19B800607P561 Metal film: 560 ohms + or - 5%, 200 VDCW, 1/8 w.				P907	192700102010	i			
Augat 340-AG39D.  Integrated circuit: 8 positions; sim to Burndy DILB 8P-108.  R901 19800607P561 Metal film: 560 ohms + or - 5%, 200 VDCW, 1/8 w.					134700102110	09-52-3032.			
XU806 19A700156P15 Integrated circuit: 8 positions; sim to Burndy DILB 8P-108.	XU801	19A700156P5	Socket, integrated circuit: 40 contacts; sim to						
DILB 8P-108.  R901 19B800607P561 Metal film: 560 ohms + or - 5%, 200 VDCW, 1/8 w.	XU806	19A700156P15	•	Q901	19A116774P3	I 1		ļ	
R901 19B800607P561 Metal film: 560 ohms + or - 5%, 200 VDCW, 1/8 w.			DILB 8P-108.			RESISTORS		l	:
				R901	19B800607P561			l	
				R902	19B800607P102	•			
					1				
									.

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circiuts are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all pervious revisions. Refer to the Parts List for the descriptions of parts affected by these revisions.

REV. C - SYNTHESIZER/INTERCONNECT BOARD 19D900961G2
To enhance transmitter operation, changed C313 and R302.

- C313 was: T644ACP310K Polyester: .010 uF +10%, 50 VDCW.
  R302 was: H212CRP322C Deposited carbon: 56K ohms +5% 1/4 w.